**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 240 A





240 A

100 V

HALF-PAK (D-67)

Single diode

HALF-PAK (D-67)

**PRODUCT SUMMARY** 

I<sub>F(AV)</sub>

 $V_R$ 

Package

Circuit

FEATURES
• 175 °C T <sub>J</sub> operation

- · Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- · Designed and qualified for industrial level
- UL approved file E222165
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

The VS-243NQ.. high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Rectangular waveform	240	А		
V <sub>RRM</sub>		100	V		
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	25 500	А		
V <sub>F</sub>	240 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.72	V		
TJ	Range	-55 to +175	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-243NQ100PbF	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	100	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	100	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 132 °C, rectangular waveform		240	
Maximum peak one cycle non-repetitive surge current	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	25 500	A
See fig. 7		10 ms sine or 6 ms rect. pulse	rated $V_{RRM}$ applied	3300	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 5.5 A, L = 1 mH		15	mJ
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1	А

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COMPLIANT





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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V <sub>FM</sub> <sup>(1)</sup>	240 A	T <sub>J</sub> = 25 °C	0.95	V
Maximum forward voltage drop		480 A		1.26	
See fig. 1		240 A	T <sub>J</sub> = 125 °C	0.72	
		480 A	1j = 125 0	0.85	
Maximum reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	6	mA
See fig. 2		T <sub>J</sub> = 125 °C	V <sub>R</sub> = naleu V <sub>R</sub>	80	
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		5500	pF
Typical series inductance	L <sub>S</sub>	From top of terminal hole to mounting plane		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs

#### Note

<sup>(1)</sup> Pulse width = 500  $\mu$ s

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperation	ature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation 0.19		°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.05	
Approximate weight				30	g
				1.06	oz.
Mounting torque	minimum		Non-lubricated threads	3 (26.5)	N ⋅ m (lbf ⋅ in)
	maximum			4 (35.4)	
Torminal torque	minimum		Non-Indificated trifeads	3.4 (30)	
Terminal torque	maximum			5 (44.2)	
Case style				HALF-PA	< module

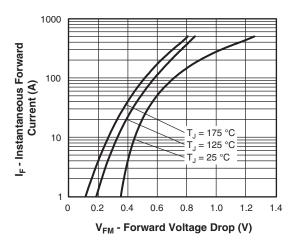


Fig. 1 - Maximum Forward Voltage Drop Characteristics

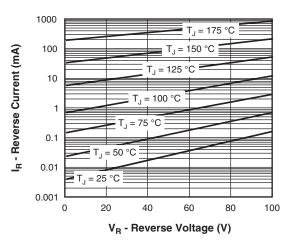


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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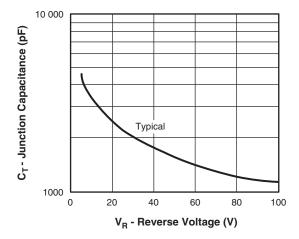


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

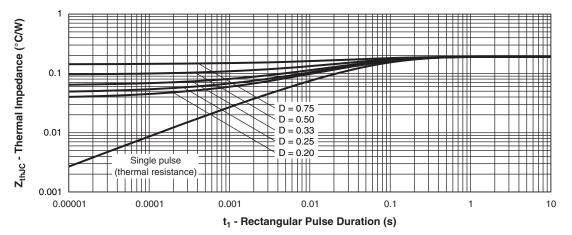


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

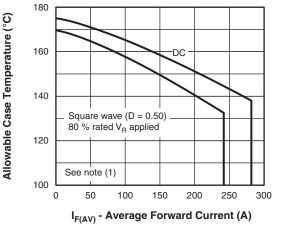


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

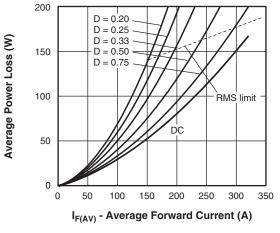


Fig. 6 - Forward Power Loss Characteristics

Revision: 19-Mar-15

3

Document Number: 94171

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## **VS-243NQ100PbF**

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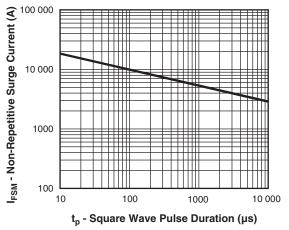
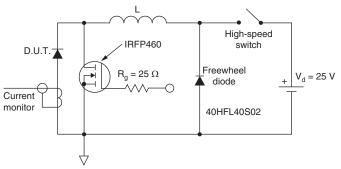


Fig. 7 - Maximum Non-Repetitive Surge Current

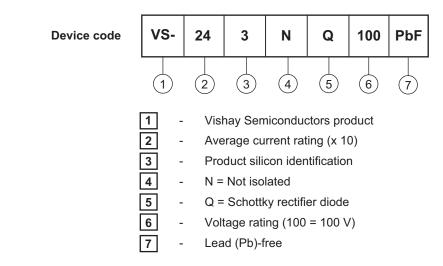


#### Fig. 8 - Unclamped Inductive Test Circuit

#### Note

- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
  - $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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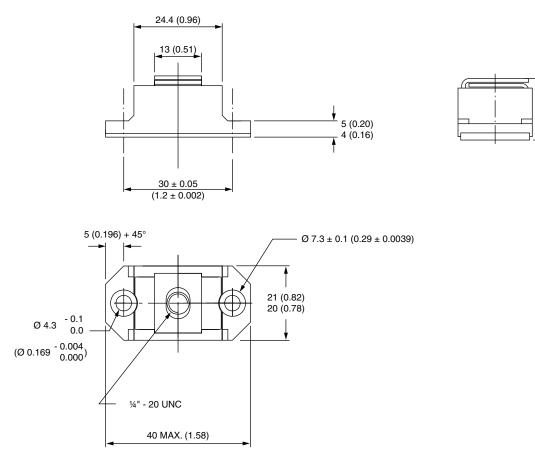
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17.5 (0.69) 16.5 (0.65)



### **DIMENSIONS** in millimeters (inches)

SHAY





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